

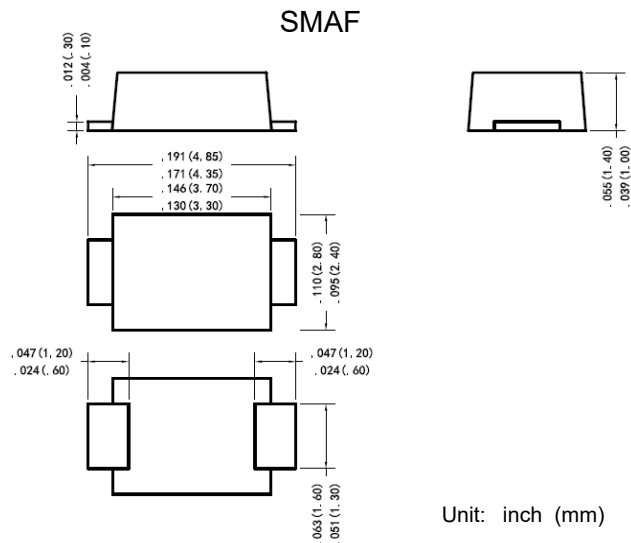
Surface Mounted Schottky Barrier Diode

Features

- Low reverse leakage
- High forward surge capability
- High reliability
- High temperature soldering guaranteed:
260°C/10seconds
- Lead and body according with RoHS standard

Mechanical Data

- Case:SMAF Molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Pure tin plated, lead free



Maximum Ratings & Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbols	SS24AF	SS26AF	SS210AF	SS215AF	SS220AF	Unit	
Maximum repetitive peak reverse voltage	V _{RRM}	40	60	100	150	200	V	
Maximum RMS voltage	V _{RMS}	28	42	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	40	60	100	150	200	V	
Maximum average forward rectified current	I _{F(AV)}	2.0					A	
Non-repetitive peak forward surge current 8.3 ms singlehalf sine-wave	I _{FSM}	50					A	
Maximum forward voltage	V _F	0.55	0.70	0.85	0.95		V	
Maximum reverse current TA= 25 TA= 100°C	I _R	500		50			μA	
		20		10			mA	
Typical thermal resistance (Note 1)	R _{θJA}	85					°C/W	
	R _{θJL}	20						
VR=4.0V,f=1MHz Type junction capacitance	C _J	120					pF	
Operating junction	T _J	-55 --- +125			-55 --- +150			°C
Storage temperature rang	T _{STG}	-55 --- +150					°C	

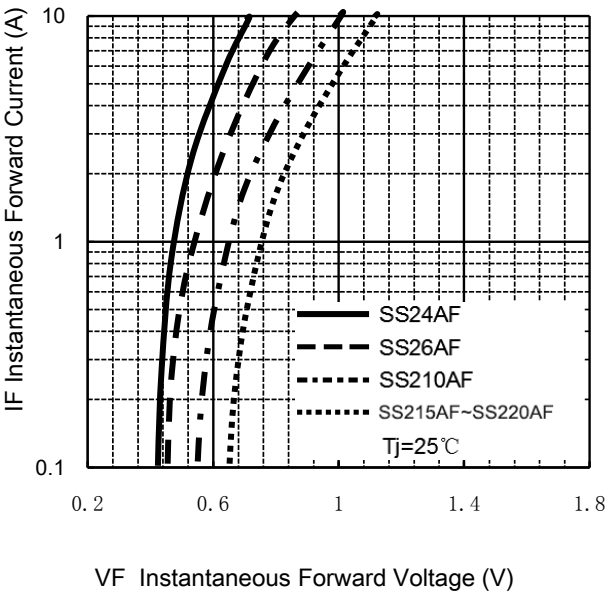
Note:

1) Thermal resistance from junction to ambient , PCB mounted.

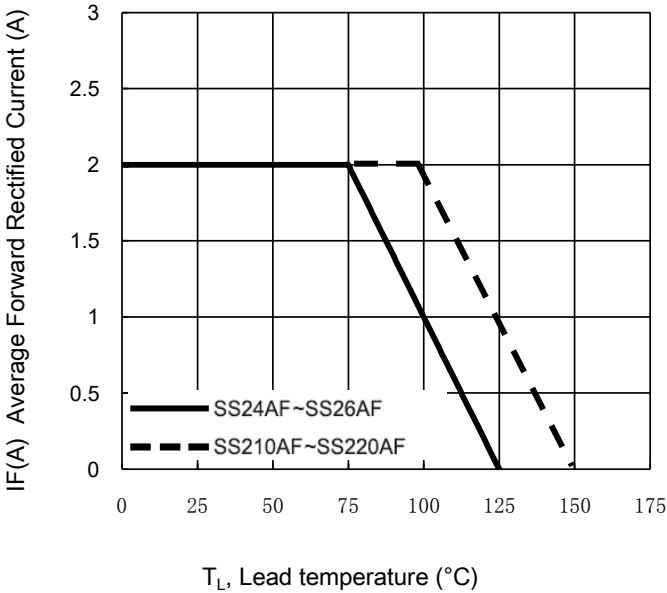


Characteristic Curves

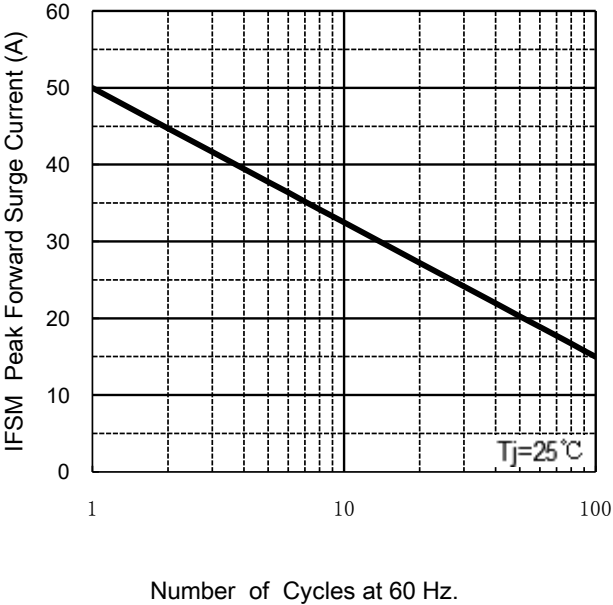
TYPICAL FORWARD CHARACTERISTIC



FORWARD CURRENT DERATING CURVE



MAXIMUM NON REPETITIVE
PEAK FORWARD SURGE CURRENT



Typical Reverse Characteristics

